

A5G35S008N

Airfast RF Power GaN Transistor

Rev. 0 — July 2021

Data Sheet: Technical Data

This 27 dBm RF power GaN transistor is designed for cellular base station applications covering the frequency range of 3300 to 3800 MHz.

3500 MHz

- Typical Single-Carrier W-CDMA Reference Circuit Performance:
 $V_{DD} = 48 \text{ Vdc}$, $I_{DQ} = 24 \text{ mA}$, $P_{out} = 27 \text{ dBm Avg.}$, Input Signal PAR = 9.9 dB @ 0.01% Probability on CCDF.(1)

Frequency	G_{ps} (dB)	η_D (%)	Output PAR (dB)	ACPR (dBc)
3300 MHz	20.9	18.3	10.1	-41.0
3400 MHz	20.9	18.0	9.9	-41.0
3500 MHz	20.9	18.0	9.8	-42.3
3600 MHz	20.2	17.9	9.7	-43.6
3700 MHz	19.3	17.6	9.6	-44.5
3800 MHz	18.4	16.7	9.6	-44.8

1. All data measured in reference circuit with device soldered to printed circuit board.

Features

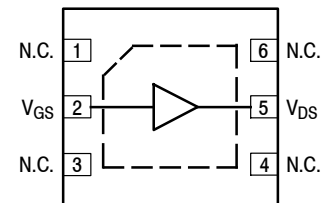
- High terminal impedances for optimal broadband performance
- Designed for low complexity analog or digital linearization systems
- Universal broadband driver
- Optimized for massive MIMO active antenna systems for 5G base stations

A5G35S008N

3300–3800 MHz, 27 dBm Avg., 48 V
AIRFAST RF POWER GaN
TRANSISTOR



DFN 4.5 × 4
PLASTIC



(Top View)

Note: Exposed backside of the package is the source terminal for the transistor.

Figure 1. Pin Connections

Table 1. Maximum Ratings

Rating	Symbol	Value	Unit
Drain- Source Voltage	V_{DSS}	125	Vdc
Gate- Source Voltage	V_{GS}	-8, 0	Vdc
Operating Voltage	V_{DD}	55	Vdc
Maximum Forward Gate Current @ $T_C = 25^\circ\text{C}$	I_{GMAX}	1.52	mA
Storage Temperature Range	T_{stg}	-65 to +150	$^\circ\text{C}$
Case Operating Temperature Range	T_C	-55 to +150	$^\circ\text{C}$
Maximum Channel Temperature	T_{CH}	225	$^\circ\text{C}$

Table 2. Recommended Operating Conditions

Rating	Symbol	Value	Unit
Operating Voltage	V_{DD}	48	Vdc

Table 3. Thermal Characteristics

Characteristic	Symbol	Value	Unit
Thermal Resistance by Infrared Measurement, Active Die Surface- to- Case Case Temperature 124.2°C , $P_D = 2.5\text{ W}$	$R_{\theta JC}$ (IR)	7.9 (1)	$^\circ\text{C/W}$
Thermal Resistance by Finite Element Analysis, Channel- to- Case Case Temperature 124.2°C , $P_D = 2.5\text{ W}$	$R_{\theta CHC}$ (FEA)	18.1 (2)	$^\circ\text{C/W}$

Table 4. ESD Protection Characteristics

Test Methodology	Class
Human Body Model (per JS- 001- 2017)	1B
Charge Device Model (per JS- 002- 2014)	C3

Table 5. Moisture Sensitivity Level

Test Methodology	Rating	Package Peak Temperature	Unit
Per JESD22- A113, IPC/JEDEC J- STD- 020	3	260	$^\circ\text{C}$

Table 6. Electrical Characteristics ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
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Off Characteristics

Off- State Drain Leakage ($V_{DS} = 150\text{ Vdc}$, $V_{GS} = -8\text{ Vdc}$)	$I_{D(BR)}$	—	—	1.52	mAdc
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On Characteristics

Gate Threshold Voltage ($V_{DS} = 10\text{ Vdc}$, $I_D = 1.6\text{ mAdc}$)	$V_{GS(th)}$	-4.6	-2.5	-1.9	Vdc
Gate Quiescent Voltage ($V_{DD} = 48\text{ Vdc}$, $I_D = 24\text{ mAdc}$, Measured in Functional Test)	$V_{GS(Q)}$	-3.0	-2.6	-2.2	Vdc
Gate- Source Leakage Current ($V_{DS} = 150\text{ Vdc}$, $V_{GS} = -12\text{ Vdc}$)	I_{GSS}	-1.52	—	—	mAdc

1. Refer to AN1955, *Thermal Measurement Methodology of RF Power Amplifiers*. Go to <http://www.nxp.com/RF> and search for AN1955.
2. $R_{\theta CHC}$ (FEA) must be used for purposes related to reliability and limitations on maximum channel temperature. MTTF may be estimated by the expression $MTTF$ (hours) = $10^{[A + B/(T + 273)]}$, where T is the channel temperature in degrees Celsius, $A = -11.6$ and $B = 9129$.

(continued)

Table 6. Electrical Characteristics ($T_A = 25^\circ\text{C}$ unless otherwise noted) (continued)

Characteristic	Symbol	Min	Typ	Max	Unit
Functional Tests ⁽¹⁾ (In NXP Production Test Fixture, 50 ohm system) $V_{DD} = 48\text{ Vdc}$, $I_{DQ} = 24\text{ mA}$, $P_{out} = 29\text{ dBm Avg.}$, $f = 3500\text{ MHz}$, 1-tone CW. [See note on correct biasing sequence.]					
Power Gain	G_{ps}	16.9	18.6	21.0	dB
Drain Efficiency	η_D	17.0	19.0	—	%
P_{out} @ 6 dB Compression Point	P6dB	38.8	39.7	—	dBm
Wideband Ruggedness ⁽²⁾ (In NXP Reference Circuit, 50 ohm system) $I_{DQ} = 24\text{ mA}$, $f = 3500\text{ MHz}$, Additive White Gaussian Noise (AWGN) with 10 dB PAR					
ISBW of 400 MHz at 55 Vdc, 7.4 W Avg. Modulated Output Power (13 dB Input Overdrive from 0.005 W Avg. Modulated Output Power)	No Device Degradation				
Typical Performance ⁽²⁾ (In NXP Reference Circuit, 50 ohm system) $V_{DD} = 48\text{ Vdc}$, $I_{DQ} = 24\text{ mA}$, 3400–3600 MHz Bandwidth					
VBW Resonance Point (IMD Third Order Intermodulation Inflection Point)	VBW_{res}	—	300	—	MHz
Gain Flatness in 200 MHz Bandwidth @ $P_{out} = 27\text{ dBm Avg.}$	G_F	—	0.5	—	dB
Fast CW, 27 ms Sweep					
P_{out} @ 6 dB Compression Point	P6dB	—	10.0	—	W
AM/PM (Maximum value measured at the P6dB compression point across the 3400–3600 MHz bandwidth)	Φ	—	-10	—	°
Gain Variation over Temperature (-40°C to +85°C)	ΔG	—	0.028	—	dB/°C
Output Power Variation over Temperature (-40°C to +85°C)	ΔP_{6dB}	—	0.005	—	dB/°C

Table 7. Ordering Information

Device	Tape and Reel Information	Package
A5G35S008NT6	T6 Suffix = 5,000 Units, 12 mm Tape Width, 13-inch Reel	DFN 4.5 × 4

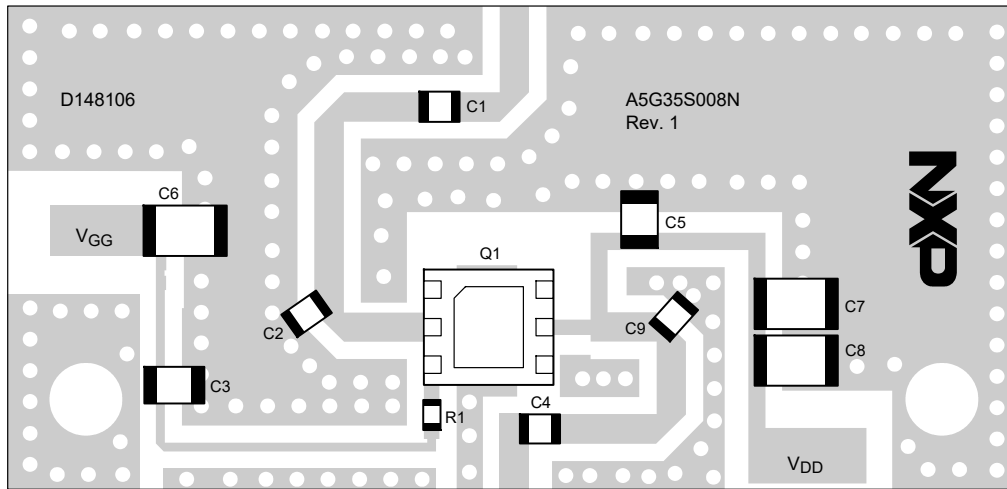
1. Part internally input matched.
2. All data measured in reference circuit with device soldered to printed circuit board.

NOTE: Correct Biasing Sequence for GaN Depletion Mode Transistors**Turning the device ON**

1. Set V_{GS} to the pinch-off voltage, typically -5 V.
2. Turn on V_{DS} to nominal supply voltage (+48 V).
3. Increase V_{GS} until I_{DS} current is attained.
4. Apply RF input power to desired level.

Turning the device OFF

1. Turn RF power off.
2. Reduce V_{GS} down to the pinch-off voltage, typically -5 V.
3. Adjust drain voltage V_{DS} to 0 V. Allow adequate time for drain voltage to reduce to 0 V from external drain capacitors.
4. Turn off V_{GS} .



Note: All data measured in reference circuit with device soldered to printed circuit board.

aaa-041821

Figure 2. A5G35S008N Reference Circuit Component Layout

Table 8. A5G35S008N Reference Circuit Component Designations and Values

Part	Description	Part Number	Manufacturer
C1, C4	10 pF Chip Capacitor	600S100JT250XT	ATC
C2	0.8 pF Chip Capacitor	600S0R8BT250XT	ATC
C3, C5	10 pF Chip Capacitor	600F100JT250XT	ATC
C6, C7, C8	4.7 μF Chip Capacitor	GRM55ER72A475KA01B	Murata
C9	0.4 pF Chip Capacitor	600S0R4BT250XT	ATC
Q1	RF Power GaN Transistor	A5G35S008N	NXP
R1	10 Ω, 1/10 W Chip Resistor	CRCW060310R0FKEA	Vishay
PCB	Rogers RO4350B, 0.020", ε _r = 3.66	D148106	MTL

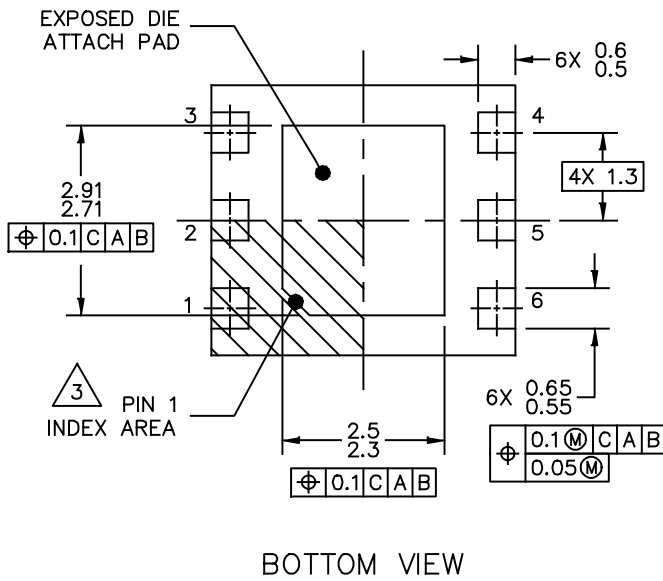
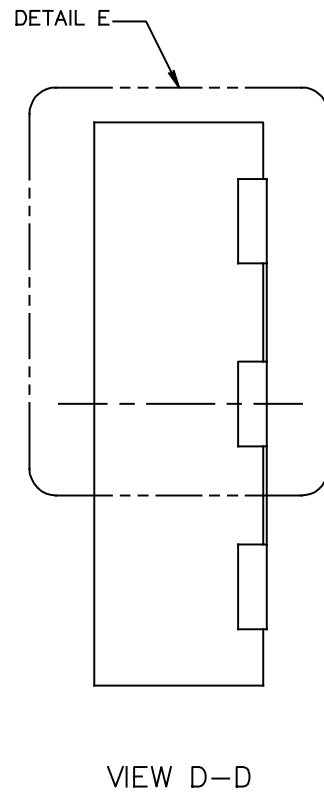
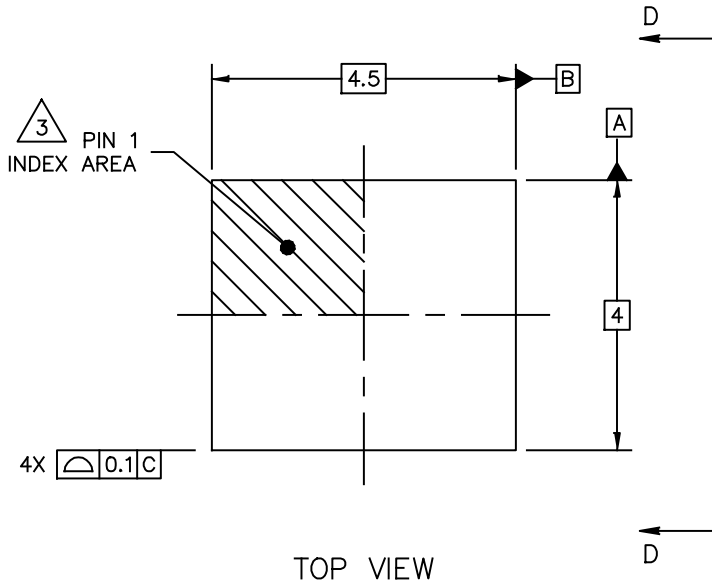


Figure 3. Product Marking

Package Information

H-PDFN-6 I/O
4.5 X 4.0 X 1.2 PKG, 1.3 PITCH

SOT2040-1



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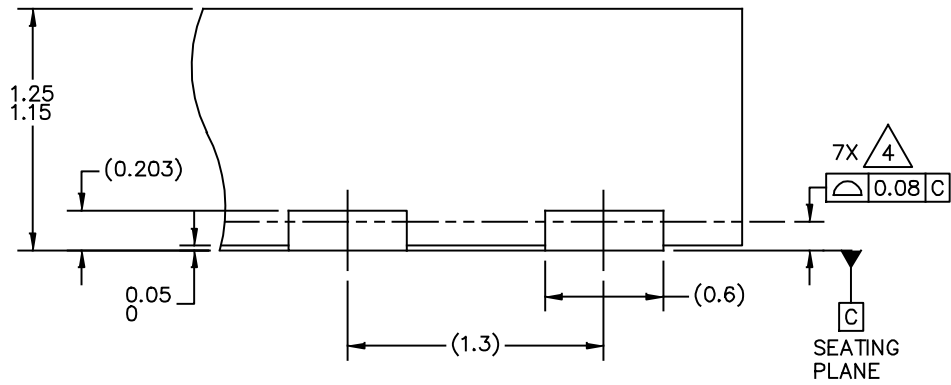
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H-PDFN-6 I/O
4.5 X 4.0 X 1.2 PKG, 1.3 PITCH

SOT2040-1



DETAIL E
VIEW ROTATED 90°CW

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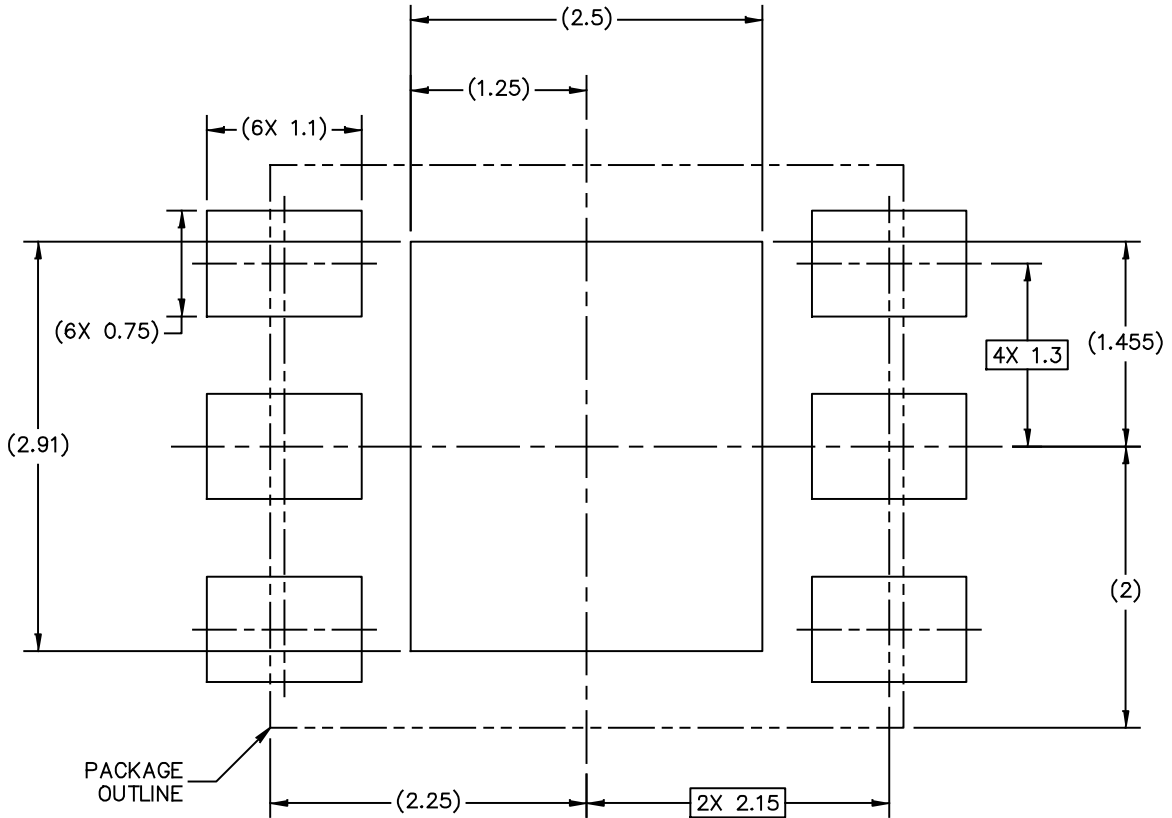
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H-PDFN-6 I/O
4.5 X 4.0 X 1.2 PKG, 1.3 PITCH

SOT2040-1



PCB DESIGN GUIDELINES – SOLDER MASK OPENING PATTERN

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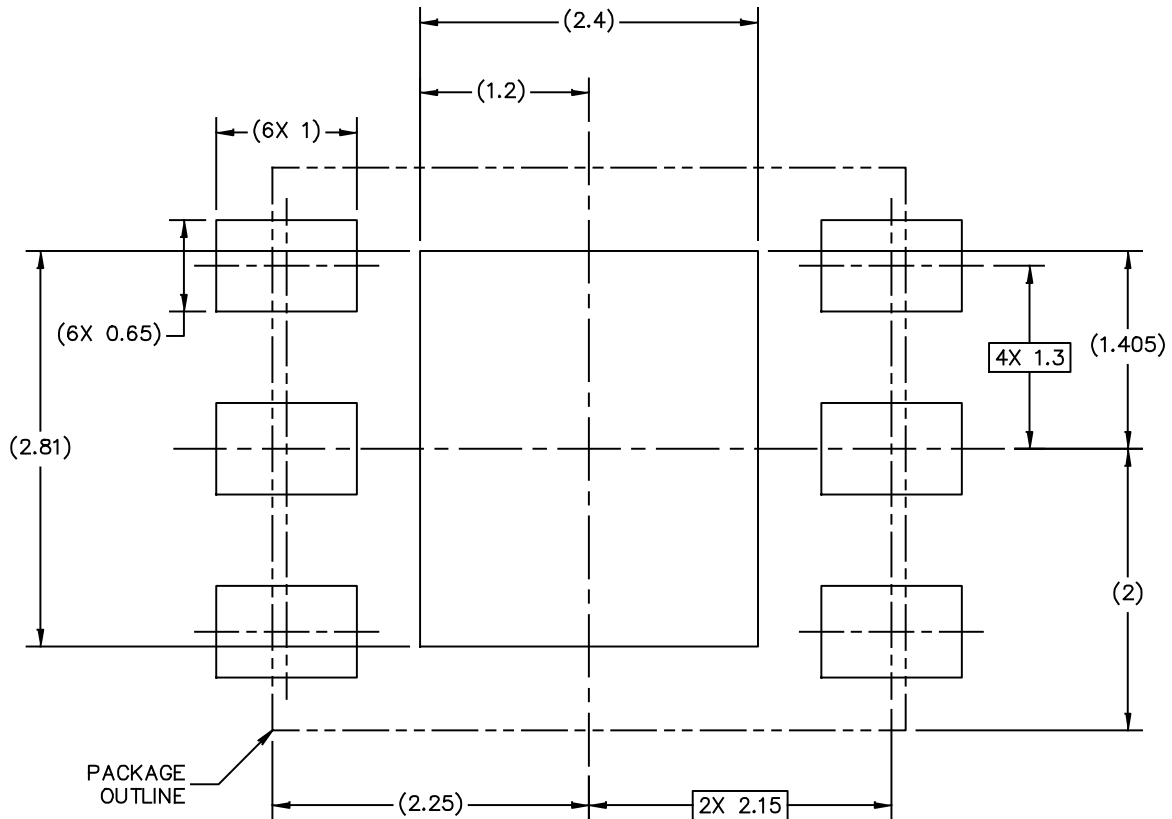
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H-PDFN-6 I/O
4.5 X 4.0 X 1.2 PKG, 1.3 PITCH

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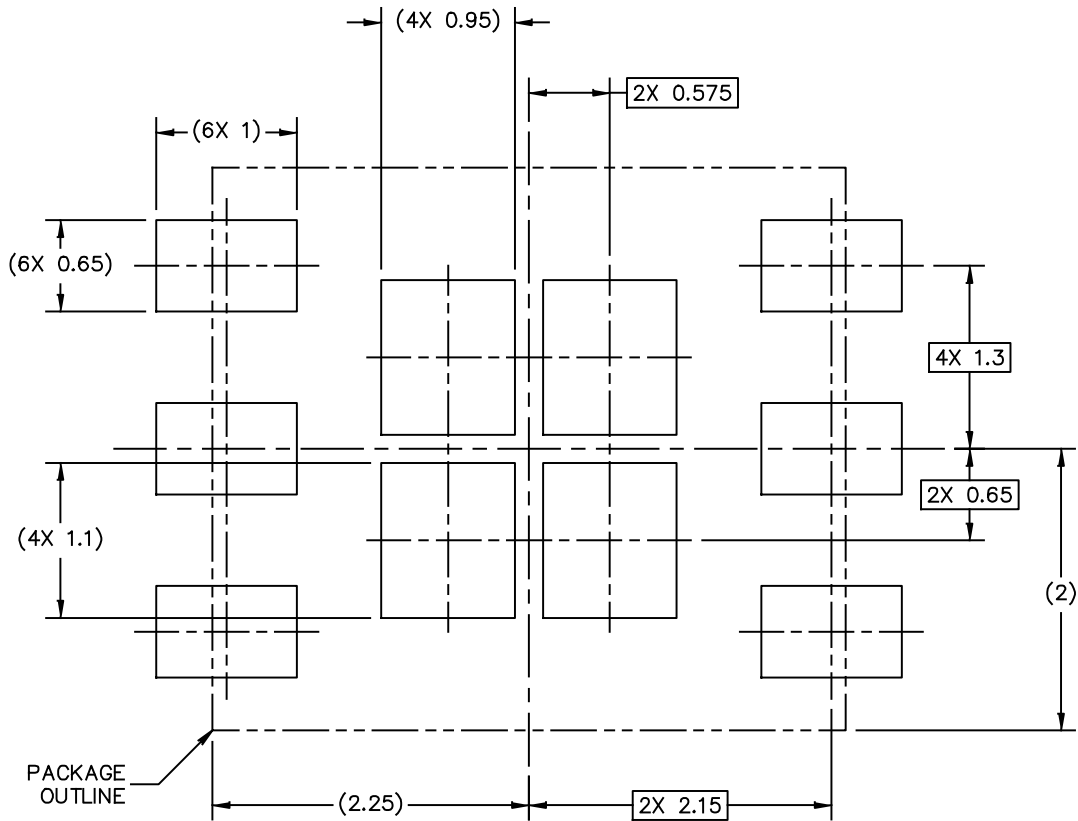
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H-PDFN-6 I/O
4.5 X 4.0 X 1.2 PKG, 1.3 PITCH

SOT2040-1



RECOMMENDED STENCIL THICKNESS 0.125 OR 0.15

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H-PDFN-6 I/O
4.5 X 4.0 X 1.2 PKG, 1.3 PITCH

SOT2040-1

NOTES:

1. ALL DIMENSIONS ARE IN MILLIMETERS.
2. DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994.
3. PIN 1 FEATURE SHAPE, SIZE AND LOCATION MAY VARY.
4. COPLANARITY APPLIES TO LEADS AND DIE ATTACH FLAG.

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Product Documentation and Software

Refer to the following resources to aid your design process.

Application Notes

- AN1907: Solder Reflow Attach Method for High Power RF Devices in Plastic Packages
- AN1955: Thermal Measurement Methodology of RF Power Amplifiers

Software

- .s2p File

Development Tools

- Printed Circuit Boards

Revision History

The following table summarizes revisions to this document.

Revision	Date	Description
0	July 2021	<ul style="list-style-type: none">• Initial release of data sheet

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Date of release: July 2021
Document identifier: A5G35S008N